

MRS120.18

Diodes module

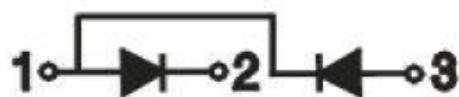
Features:

- International standard package
- Low forward voltage drop
- Isolation voltage 3000V ~
- Simple mounting
- UL recognized, file no. E312789

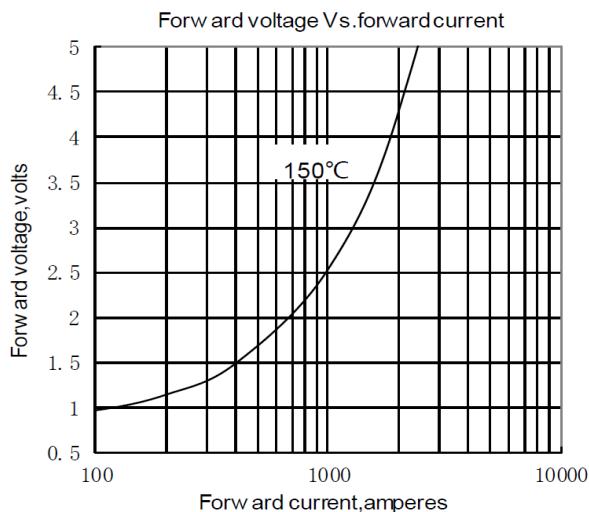
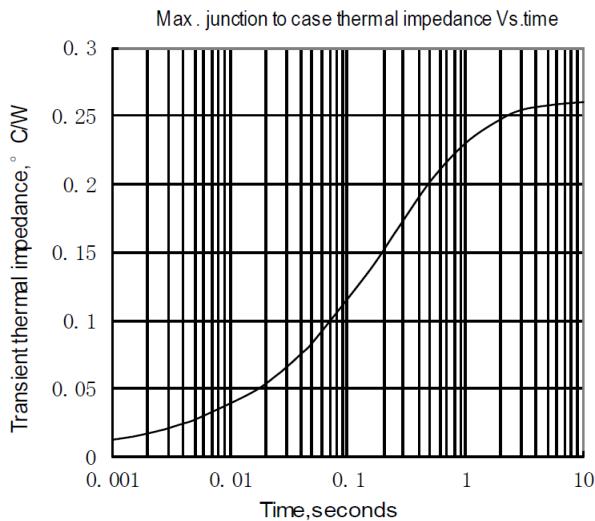
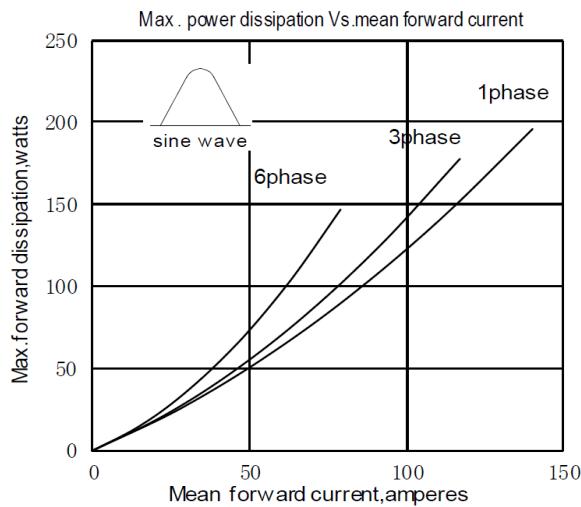
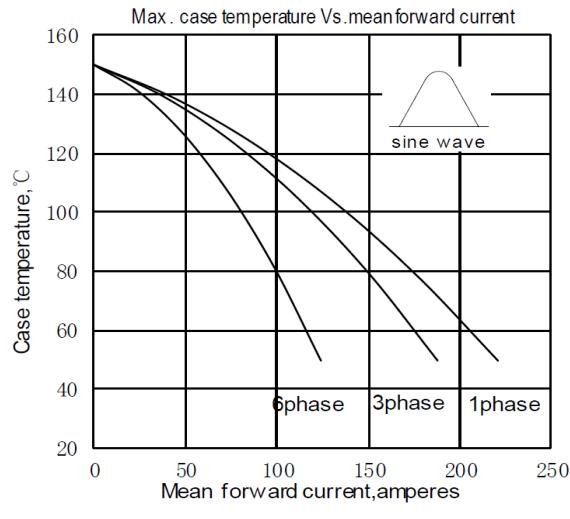
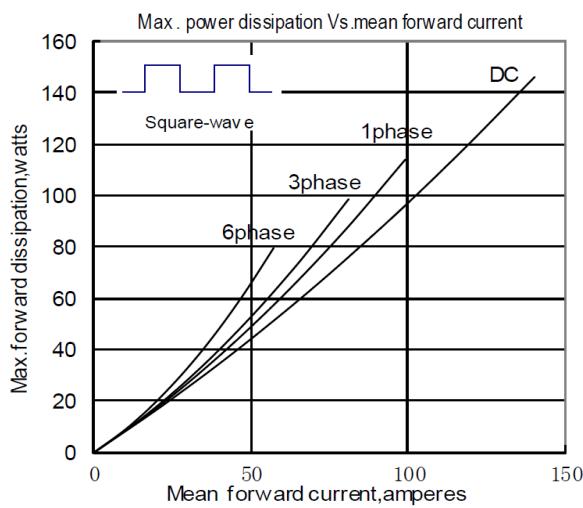
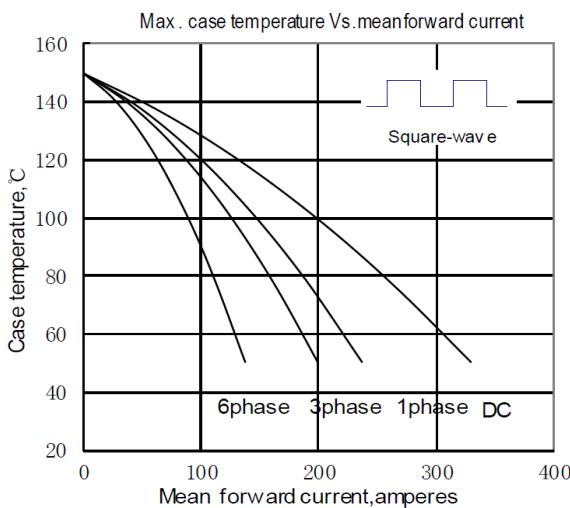


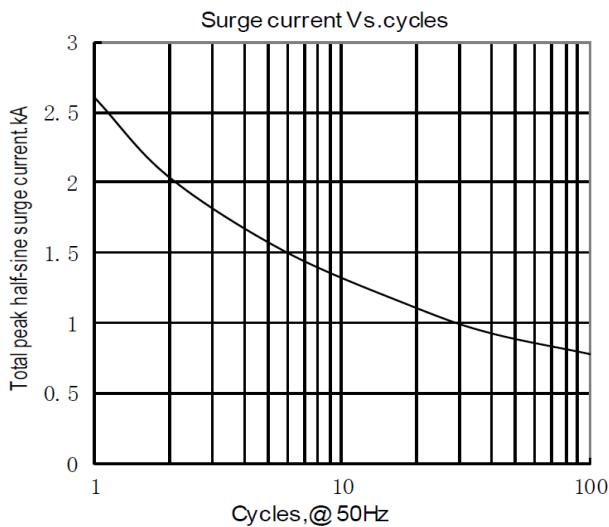
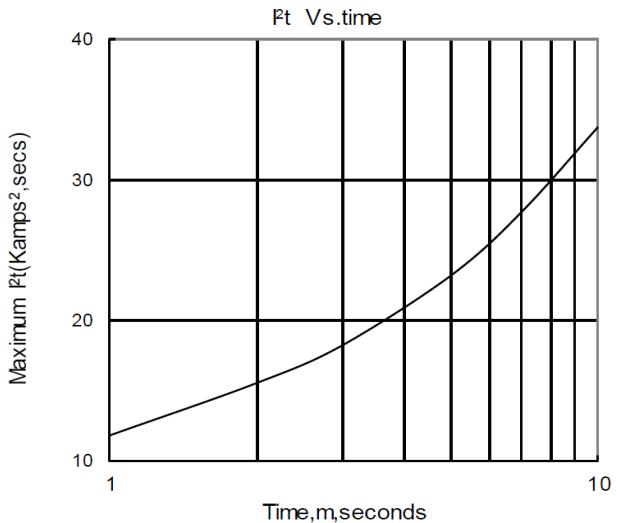
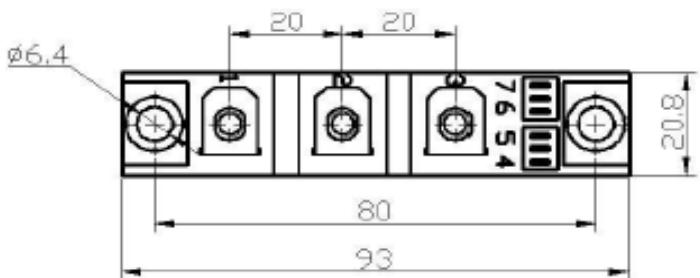
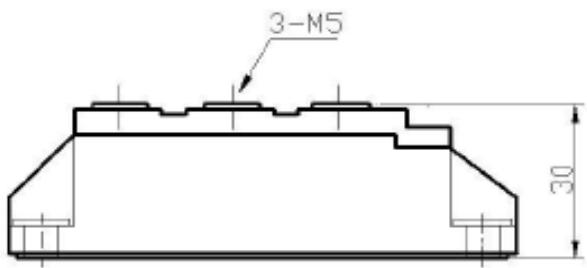
Typical applications:

- Various rectifier power
- AC/DC motor control
- Heater control
- Frequency converters



Symbol	Characteristics	Test Conditions	Value			Unit
			Min	Typ	Max	
$V_{RSM/DSM}$	Non-repetitive reverse/forward blocking voltage	$T_j = 25^\circ C$			1900	V
$V_{RRM/DRM}$	Repetitive reverse/forward blocking voltage	$T_j = 25^\circ C$			1800	V
$I_{F(AV)}$	Forward average current	180° half sine wave 50Hz $T_c = 115^\circ C$ (100 °C)			120(140)	A
$I_{F(RMS)}$	Forward square root current	180° half sine wave 50Hz $T_c = 100$ °C			220	A
I_{RRM} I_{DRM}	Repetitive peak current	at V_{DRM}/V_{RRM} $T_j = 150^\circ C$			10	mA
I_{FSM}	Forward surge current	10ms half sine wave, $T_j = 45^\circ C$			2600	A
I^2t	I^2t for fusing coordination	$V_R = 0.6 V_{RRM}$, $T_j = 45^\circ C$			33000	A²s
V_{FO}	Threshold voltage	$T_j = 150^\circ C$			0.80	V
r_T	Forward slope resistance	$T_j = 150^\circ C$			1.74	mΩ
V_{FM}	Peak forward voltage	$T=25^\circ C$; $I_T=330A$			1.45	V
$R_{th(j-c)}$	Thermal resistance junction to case	Single side cooled per chip			0.26	°C/W
$R_{th(c-s)}$	Thermal resistance case to sink	Single side cooled per chip			0.20	°C/W
V_{ISO}	Isolation voltage	50Hz, RMS, t = 1min			3000	V
F_M	Mounting torque - copper plate (M6)		4		6	N·m
	Mounting torque - terminal (M5)		2.5		4.5	N·m
T_{stg}	Storage Temperature		-40		150	°C
T_j	Operating Temperature		-40		150	°C
W_t	Weight			175		g
Outline	223F3					

MRS120.18

Fig.1

Fig.2

Fig.3

Fig.4

Fig.5

Fig.6


Fig.7

Fig.8

(dimensions in mm)
S.C.O.M.E.S. Srl

Via Enrico Mattei, 6/8 - 26283 - Castiglione d'Adda (LO) - Italy

Phone: +39 0377 901243 Fax: +39 0377 900206